

# **PN3644**



# **PNP General Purpose Amplifier**

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 500 mA. Sourced from Process 63. See PN2907A for characteristics.

# **Absolute Maximum Ratings\***

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V <sub>CEO</sub>	Collector-Emitter Voltage	45	V	
Vcво	Collector-Base Voltage 45		V	
V <sub>EBO</sub>	Emitter-Base Voltage 5.0		V	
Ic	Collector Current - Continuous	800	mA	
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C	

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

# **Thermal Characteristics**

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		PN3644	
$P_D$	Total Device Dissipation	625	mW
	Derate above 25°C	5.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

# PNP General Purpose Amplifier (continued)

Symbol	Parameter	Test Conditions	Min	Max	Units
OEE CHA	RACTERISTICS				
		I 10 m 1 0	45		V
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage*	$I_C = 10 \text{ mA}, I_B = 0$	45		V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$	45		V
√ <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 10 \mu A, I_C = 0$	5.0		V
CES	Collector-Cutoff Current	$V_{CB} = 30 \text{ V}, I_{E} = 0$		35	nA
		$V_{CB} = 30 \text{ V}, I_E = 0, T_A = 65 ^{\circ}\text{C}$		2.0	μΑ
BL	Base-Cutoff Current	$V_{CE} = 30 \text{ V}, I_{C} = 0$		35	nA
ON CHAF	RACTERISTICS*				
η <sub>EE</sub>	DC Current Gain	$V_{CE} = 10 \text{ V}, I_{C} = 0.1 \text{ mA}$	40		
		$V_{CE} = 10 \text{ V}, I_{C} = 1.0 \text{ mA}$	80		
		$V_{CE} = 10 \text{ V}, I_{C} = 10 \text{ mA}$	100		
		$V_{CE} = 10 \text{ V}, I_{C} = 150 \text{ mA}$	100	300	
		$V_{CE} = 2.0 \text{ V}, I_{C} = 300 \text{ mA}$	20	040	
	Oallandar Freitten Oatsmatian Walterna	V <sub>CE</sub> = 1.0 V, I <sub>C</sub> = 50 mA	80	240	
VCE(sat)	Collector-Emitter Saturation Voltage	$I_C = 50 \text{ mA}, I_B = 2.5 \text{ mA}$ $I_C = 150 \text{ mA}, I_B = 15 \text{ mA}$		0.25 0.4	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	$I_C = 50 \text{ mA}, I_B = 15 \text{ mA}$		1.0	V
VBE(Sat)	Base Emitter Saturation Voltage	$I_C = 150 \text{ mA}, I_B = 15 \text{ mA}$		1.3	v
SMALL S	IGNAL CHARACTERISTICS				
Cob	Output Capacitance	V <sub>CB</sub> = 10 V, f = 140 kHz		8.0	pF
Cib	Input Capacitance	V <sub>BE</sub> = 0.5 V, f = 140 kHz		35	pF
h <sub>fe</sub>	Small-Signal Current Gain	I <sub>C</sub> = 20 mA, V <sub>CE</sub> = 20 V,	2.0		'
116	3	f = 100 MHz			
CWITCHI	NG CHARACTERISTICS				
		T	<u> </u>	1 40	1
SWITCHI	Turn-on Time	$V_{CC} = 30 \text{ V}, I_C = 300 \text{ mA},$		40	ns
ton			1	25	ns
	Delay Time	I <sub>B1</sub> = 30 mA		_	_
ton	Delay Time Rise Time			35	ns
ton t <sub>d</sub>	Delay Time Rise Time Turn-off Time	Vcc = 30 V, Ic = 300 mA		35 100	_
ton td	Delay Time Rise Time			35	ns

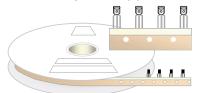
<sup>\*</sup>Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%

### **TO-92 Tape and Reel Data** FAIRCHILD SEMICONDUCTOR TM **TO-92 Packaging** Configuration: Figure 1.0 **TAPE and REEL OPTION** FSCINT Label sample See Fig 2.0 for various Reeling Styles CBVK//418019 **FSCINT** Label 5 Reels per Intermediate Box Customized F63TNR Label sample Label F63TNR LOT: CBVK741B019 QTY: 2000 FSID: PN222N Customized QTY1: QTY2: Label 375mm x 267mm x 375mm Intermediate Box TO-92 TNR/AMMO PACKING INFROMATION **AMMO PACK OPTION** See Fig 3.0 for 2 Ammo Packing Style Quantity EOL code **Pack Options** 2,000 D26Z Е 2,000 D27Z Ammo М 2,000 D74Z D75Z 2,000 **FSCINT** Unit weight = 0.22 gm Reel weight with components = 1.04 kg Ammo weight with components = 1.02 kg Max quantity per intermediate box = 10,000 units Label 5 Ammo boxes per Intermediate Box 327mm x 158mm x 135mm Immediate Box Customized F63TNR Customized Label Label 333mm x 231mm x 183mm Intermediate Box (TO-92) BULK PACKING INFORMATION **BULK OPTION** See Bulk Packing DESCRIPTION QUANTITY Information table J18Z TO-18 OPTION STD 2.0 K / BOX Anti-static Bubble Sheets TO-5 OPTION STD NO LEAD CLIP 1.5 K / BOX J05Z **FSCINT Label** NO EOL TO-92 STANDARD STRAIGHT FOR: PKG 92, NO LEADCLIP 2.0 K / BOX 94 (NON PROELECTRON SERIES), 96 TO-92 STANDARD STRAIGHT FOR: PKG 94 (PROELECTRON SERIES BCXXX, BFXXX, BSRXXX), 97, 98 L34Z NO LEADCLIP 2.0 K / BOX 2000 units per 114mm x 102mm x 51mm EO70 box for std option Immediate Box 5 EO70 boxes per intermediate Box 530mm x 130mm x 83mm Customized Intermediate box Label FSCINT Label 10,000 units maximum per intermediate box for std option

# TO-92 Tape and Reel Data, continued

# **TO-92 Reeling Style Configuration:** Figure 2.0

### Machine Option "A" (H)

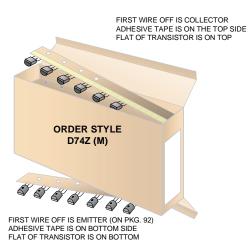


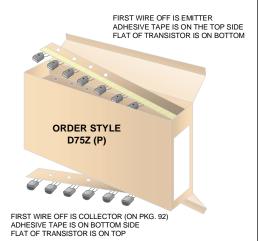
Style "A", D26Z, D70Z (s/h)

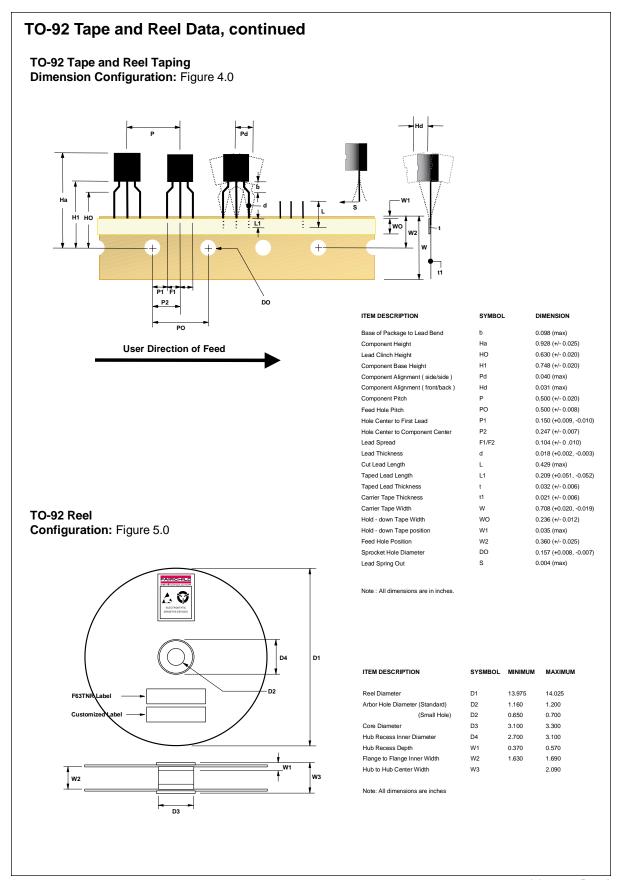
# Machine Option "E" (J)

Style "E", D27Z, D71Z (s/h)

# **TO-92 Radial Ammo Packaging Configuration:** Figure 3.0



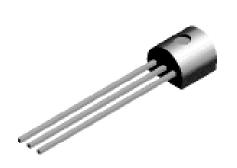


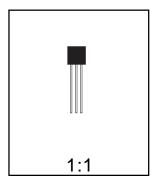


# **TO-92 Package Dimensions**



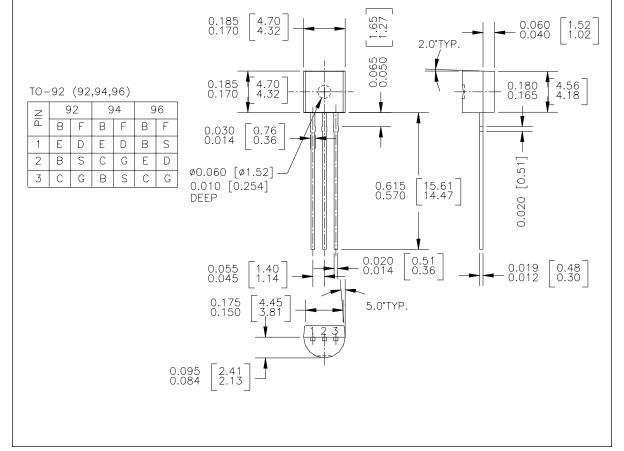
# TO-92 (FS PKG Code 92, 94, 96)





Scale 1:1 on letter size paper
Dimensions shown below are in:
inches [millimeters]

Part Weight per unit (gram): 0.1977



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